

Al-Mustaqbal University / College of Engineering & Technology
Department (Communication Technical Engineering)
Class (First)
Subject (ELECTRONIC CIRCUITS)/ Code/ UOMU028022)
(Lecturer (Prof.Dr.Haider J Abd)
2nd term – Lecture No. & Lecture Name (Lec 6: Bias Stabilization)

Bias Stabilization

Basic Definitions:

The stability of system is a measure of sensitivity of a circuit to variations in its parameters. In any amplifier employing a transistor the **collector current I_C** is sensitive to each of the following parameters:

- ◀ **I_{CO} (reverse saturation current): doubles in value for every 10°C increase in temperature.**
- ◀ **$|V_{BE}|$ (base-to-emitter voltage): decrease about 7.5 mV per 1°C increase in temperature.**
- ◀ **β (forward current gain): increase with increase in temperature.**

Any or all of these factors can cause the bias point to drift from the design point of operation.

Stability Factors, $S(I_{CO})$, $S(V_{BE})$, and $S(\beta)$:

A stability factor, S , is defined for each of the parameters affecting bias stability as listed below:

$$S(I_{CO}) = \frac{\Delta I_C}{\Delta I_{CO}} = \frac{\partial I_C}{\partial I_{CO}} \bigg|_{V_{BE}, \beta = \text{const.}} \quad [10.1a]$$

$$S(V_{BE}) = \frac{\Delta I_C}{\Delta V_{BE}} = \frac{\partial I_C}{\partial V_{BE}} \bigg|_{I_{CO}, \beta = \text{const.}} \quad [10.1b]$$

$$S(\beta) = \frac{\Delta I_C}{\Delta \beta} = \frac{\partial I_C}{\partial \beta} \bigg|_{I_{CO}, V_{BE} = \text{const.}} \quad [10.1c]$$

Generally, networks that are quite stable and relatively insensitive to temperature variations have low stability factors. In some ways it would seem more appropriate to consider the quantities defined by Eqs. [10.1a - 10.1c] to be sensitivity factors because: the higher the stability factor, the more sensitive the network to variations in that parameter.

The total effect on the collector current can be determined using the following equation:

$$\Delta I_C = S(I_{CO})\Delta I_{CO} + S(V_{BE})\Delta V_{BE} + S(\beta)\Delta\beta \quad [10.2]$$

Derivation of Stability Factors for Standard Bias Circuits:

For the **voltage-divider bias circuit**, the exact analysis (using Thevenin theorem) for the input (base-emitter) loop will result in:

$$\begin{aligned} E_{Th} - I_B R_{Th} - V_{BE} - I_E R_E &= 0, \\ \text{and } I_E &= I_C + I_B \Rightarrow \\ I_C R_E + I_B (R_E + R_{Th}) + V_{BE} &= E_{Th}, \\ \text{and } I_C &= \beta I_B + (\beta + 1) I_{CO}, \\ \text{or } I_B &= \frac{I_C}{\beta} - \frac{\beta + 1}{\beta} I_{CO} \Rightarrow \end{aligned}$$

$$I_C \left[\frac{(\beta + 1) R_E + R_{Th}}{\beta} \right] - I_{CO} \left[\frac{(\beta + 1)(R_E + R_{Th})}{\beta} \right] + V_{BE} = E_{Th} \quad [10.3]$$

The partial derivation of the Eq. [10.3] with respect to I_{CO} will result:

$$\begin{aligned} \frac{\partial I_C}{\partial I_{CO}} \cdot \frac{(\beta + 1) R_E + R_{Th}}{\beta} - \frac{(\beta + 1)(R_E + R_{Th})}{\beta} &= 0 \\ S(I_{CO}) &= \frac{(\beta + 1)(R_E + R_{Th})}{(\beta + 1) R_E + R_{Th}} \end{aligned} \quad [10.4a]$$

Also, the partial derivation of the Eq. [10.3] with respect to V_{BE} will result:

$$\begin{aligned} \frac{\partial I_C}{\partial V_{BE}} \cdot \frac{(\beta + 1) R_E + R_{Th}}{\beta} + 1 &= 0 \\ S(V_{BE}) &= \frac{-\beta}{(\beta + 1) R_E + R_{Th}} \end{aligned} \quad [10.4b]$$

The mathematical development of the last stability factor $S(\beta)$ is more complex than encountered for $S(I_{CO})$ and $S(V_{BE})$. Thus, $S(\beta)$ is suggested by the following equation:

$$S(\beta) = \frac{(I_{C_1} / \beta_1)(R_E + R_{Th})}{(\beta_2 + 1) R_E + R_{Th}} \quad [10.4c]$$

For the **emitter-stabilized bias circuit**, the stability factors are the same as these obtained above for the voltage-divider bias circuit except that R_{Th} will be replaced by R_B . These are:

$$S(I_{CO}) = \frac{(\beta + 1)(R_E + R_B)}{(\beta + 1)R_E + R_B} \quad [10.5a]$$

$$S(V_{BE}) = \frac{-\beta}{(\beta + 1)R_E + R_B} \quad [10.5b]$$

$$S(\beta) = \frac{(I_{C_1} / \beta_1)(R_E + R_B)}{(\beta_2 + 1)R_E + R_B} \quad [10.5c]$$

For the **fixed-bias circuit**, if we plug in $R_E = 0$ the following equation will result:

$$S(I_{CO}) = \beta + 1 \quad [10.6a]$$

$$S(V_{BE}) = -\frac{\beta}{R_B} \quad [10.6b]$$

$$S(\beta) = \frac{I_{C_1}}{\beta_1} \quad [10.6c]$$

Finally, for the case of the **voltage-feedback bias circuit**, the following equation will result:

$$S(I_{CO}) = \frac{(\beta + 1)(R_C + R_E + R_B)}{(\beta + 1)(R_C + R_E) + R_B} \quad [10.7a]$$

$$S(V_{BE}) = \frac{-\beta}{(\beta + 1)(R_C + R_E) + R_B} \quad [10.7b]$$

$$S(\beta) = \frac{(I_{C_1} / \beta_1)(R_C + R_E + R_B)}{(\beta_2 + 1)(R_C + R_E) + R_B} \quad [10.7c]$$

Example 10-1:

1. Design a voltage-divider bias circuit using a V_{CC} supply of +18 V, and an npn silicon transistor with β of 80. Choose $R_C = 5R_E$, and set I_C at 1 mA and the stability factor $S(I_{CO})$ at 3.8.
2. For the circuit designed in part (1), determine the change in I_C if a change in operating conditions results in I_{CO} increasing from 0.2 to 10 μA , V_{BE} drops from 0.7 to 0.5 V, and β increases 25%.
3. Calculate the change in I_C from 25° to 75°C for the same circuit designed in part (1), if $I_{CO} = 0.2 \mu\text{A}$ and $V_{BE} = 0.7 \text{ V}$.

Solution:

Part 1:

$$V_{CE} = V_{CC} / 2 = 18 / 2 = 9 \text{ V}.$$

$$V_{CE} = V_{CC} - I_C(R_C + R_E), \quad R_C = 5R_E \Rightarrow$$

$$9 = 18 - (1\text{m})(5R_E + R_E) \Rightarrow R_E = 1.5 \text{ k}\Omega.$$

$$R_C = 5(1.5 \text{ k}) = 7.5 \text{ k}\Omega.$$

$$I_E \cong I_C = 1 \text{ mA}, \quad V_E = I_E R_E = (1\text{m})(1.5 \text{ k}) = 1.5 \text{ V}.$$

$$V_B = V_E + V_{BE} = 1.5 + 0.7 = 2.2 \text{ V}.$$

$$V_B = \frac{R_2 V_{CC}}{R_1 + R_2} \Rightarrow \boxed{\frac{R_2}{R_1 + R_2} = \frac{V_B}{V_{CC}} = \frac{2.2}{18}} \quad [10.8a]$$

$$S(I_{CO}) = \frac{(\beta + 1)(R_E + R_{Th})}{(\beta + 1)R_E + R_{Th}} \Rightarrow$$

$$3.8 = \frac{(81)(1.5 \text{ k} + R_{Th})}{(81)(1.5 \text{ k}) + R_{Th}} \Rightarrow R_{Th} = 4.4 \text{ k}\Omega.$$

$$R_{Th} = \frac{R_1 R_2}{R_1 + R_2} \Rightarrow \boxed{\frac{R_2}{R_1 + R_2} = \frac{R_{Th}}{R_1} = \frac{4.4 \text{ k}}{R_1}} \quad [10.8b]$$

From Eqs. [10.8a] and [10.8b]:

$$\frac{4.4 \text{ k}}{R_1} = \frac{2.2}{18} \Rightarrow R_1 = 36 \text{ k}\Omega.$$

From Eq. [10.8a]:

$$\frac{R_2}{36 \text{ k} + R_2} = \frac{2.2}{18} \Rightarrow R_2 = 5 \text{ k}\Omega.$$

Fig. 10-1 shows the final circuit.

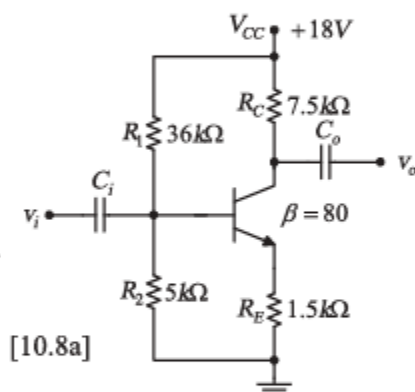


Fig. 10-1